NSN 5961-01-382-4877

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Diode Semiconductor Device - Page 1 of 1



View Online at https://aerobasegroup.com/nsn/5961-01-382-4877 **Inclosure Material:** Plastic **Overall Length:** 2.660 inches **Mounting Facility Quantity: Mounting Method:** Unthreaded hole **Criticality Code Justification:** Feat **Semiconductor Material:** Silicon Voltage Rating In Volts Per Characteristic: 75.0 working peak reverse voltage, peak total value **Maximum Operating Tempurature Per Measurement Point:** 200.0 degrees celsius ambient air and 200.0 degrees celsius case **Special Features:** Selected item p/n jantx1n4148-1 per mil-s-19500/116 and requirements in drawing no.9042817 cage 98747: hci **Nuclear Hardness Critical Feature:** Hardened **Terminal Type And Quantity:** 2 uninsulated wire lead Shelf Life: N/a **Unit Of Measure: Demilitarization:** No Fiig: